

MIPI 2.0 SP6T switch for LTE diversity, Tx and LAA applications

Key Features

- 0.1 to 6 GHz coverage for LTE and LAA application
- LTE TX power handling capabilities
- Ultra low insertion loss: 0.65dB at Band 42
- Small form factor 1.1mm x 1.9mm
- Fully compatible with MIPI 2.0 RFFE standard
- No decoupling capacitors required (Unless DC applied on RF lines)

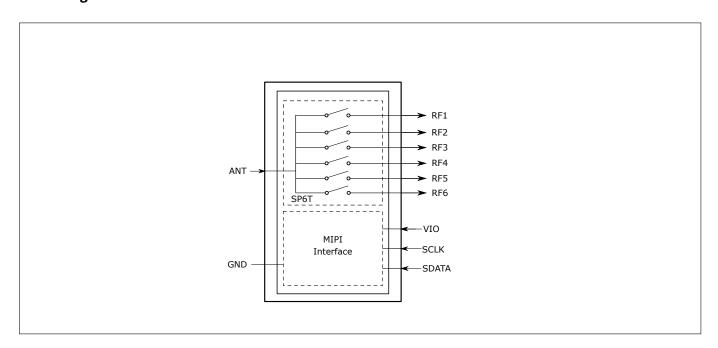
Applications

The SP6T switch is a band selection switch for LTE applications. With LTE TX power handling capability it is suitable for both LTE diversity path and LTE uplink Tx applications. The switch covers up to 6 GHz, so it covers Band 42, Band 43 and LAA.

Product Validation

Qualified for industrial applications according to the relevant tests of JEDEC47/20/22.

Block diagram



Data Sheet www.infineon.com

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Features

1 Features

- 0.1 to 6 GHz coverage for LTE and LAA application
- Suitable for LTE / WCDMA / TDCDMA Applications
- LTE TX power handling capabilities
- Ultra low insertion loss: 0.65dB at Band 42
- Small form factor 1.1mm x 1.9mm
- Fully compatible with MIPI 2.0 RFFE standard
- No decoupling capacitors required (Unless DC applied on RF lines)
- Low harmonic generation
- High port-to-port-isolation
- On chip control logic including ESD protection
- No power supply blocking required
- High EMI robustness
- RoHS and WEEE compliant package





Description

This SP6T RF switch is a perfect solution for multimode handsets based on LTE and WCDMA. It is based on Infineon?s proprietary technology and has excellent RF performance. The ultra-low insertion loss helps customers to achieve high system sensitivity, the coverage of LTE Tx power and 6 GHz enables very broad application. It features DC-free RF ports, external DC blocking capacitors at the RF ports are only required if DC voltage is applied externally. Its on chip MIPI RFFE 2.0 controller is fully compatible with industry standard.





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Maximum Ratings

2 Maximum Ratings

Table 1: Maximum Ratings, Table I at T_A = 25 °C, unless otherwise specified

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Тур.	Max.		
Frequency Range	f	0.1	_	6.0	GHz	1)
Supply voltage ²⁾	V _{IO}	0	-	2.1	V	-
Storage temperature range	T _{STG}	-55	-	150	°C	-
RF input power at all TRx ports	P _{RF_max}	-	-	35	dBm	Short momentary / 50Ω
ESD capability, CDM ⁴⁾	$V_{ESD_{CDM}}$	-500	_	+500	V	
ESD capability, HBM ⁵⁾	$V_{ESD_{HBM}}$	-1	-	+1	kV	
ESD capability, system level (RF port) 6)	V _{ESD_{ANT}}	-8	_	+8	kV	ANT vs system GND, with 27 nH
						shunt inductor
Junction temperature	Tj	-	-	125	°C	-

¹⁾ Switch has a low-pass response. For higher frequencies, losses have to be considered for their impact on thermal heating. The DC voltage at RF ports V_{RFDC} has to be 0V.

Warning: Stresses above the max. values listed here may cause permanent damage to the device. Maximum ratings are absolute ratings; exceeding only one of these values may cause irreversible damage to the integrated circuit. Exposure to conditions at or below absolute maximum rating but above the specified maximum operation conditions may affect device reliability and life time. Functionality of the device might not be given under these conditions.

Table 2: Maximum Ratings, Table II at T_A = $25\,^{\circ}$ C, unless otherwise specified

Parameter	Symbol Values			!S	Unit	Note / Test Condition	
		Min.	Тур.	Max.			
Thermal resistance junction - soldering point	R _{thJS}	_	-	62	K/W	-	
Maximum DC-voltage on RF-Ports and	V _{RFDC}	0	_	0	V	No DC voltages allowed on RF-	
RF-Ground						Ports	

²⁾ Note: Consider any ripple voltages on top of V_{IO} . Including RF ripple, V_{IO} must not exceed the maximum ratings: $V_{IO} = V_{DC} + V_{Ripple}$.

⁴⁾ Field-Induced Charged-Device Model ANSI/ESDA/JEDEC JS-002. Simulates charging/discharging events that occur in production equipment and processes. Potential for CDM ESD events occurs whenever there is metal-to-metal contact in manufacturing.

⁵⁾ Human Body Model ANSI/ESDA/JEDEC JS-001 ($R = 1.5 \text{ k}\Omega$, C = 100 pF).

 $^{^{6)}}$ IEC 61000-4-2 ($R=330~\Omega, C=150~\mathrm{pF}$), contact discharge.

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Operation ranges

3 Operation ranges

Table 3: Operation ranges at $T_{\rm A}$ = -40 °C to 85 °C

Parameter	Symbol Values				Unit	Note / Test Condition	
		Min.	Тур.	Max.			
Supply voltage	V _{IO}	1.65	1.8	1.95	V	_	
RFFE input high voltage ¹	V _{IH}	0.7*V _{IO}	_	V _{IO}	V	_	
RFFE input low voltage ¹	V _{IL}	0	_	0.3*V _{IO}	V	_	
RFFE output high voltage ¹	V _{OH}	0.8*V _{IO}	_	V _{IO}	V	_	
RFFE output low voltage ¹	V _{OL}	0	_	0.2*V _{IO}	V	_	
RFFE control input capacitance	C _{Ctrl}	_	_	2	pF	_	
Supply current	I _{VIO}	_	2	_	μΑ	Idle State	
Supply current	I _{VIO}	_	60	125	μΑ	Operation state	

¹SCLK and SDATA

Table 4: RF input power

Parameter	Symbol	Values		Values		Values		Note / Test Condition
		Min.	Тур.	Max.				
RF input power on TRX ports	P_{RF}	-	-	32	dBm	CW / VSWR 1:1 / 25 °C		
RF input power on TRX ports	P_{RF}	-	-	30	dBm	CW / VSWR 6:1 / 25 °C		

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RF Characteristics

4 RF Characteristics

Table 5: RF Characteristics at $T_A = -40 \,^{\circ}\text{C}...85 \,^{\circ}\text{C}$, $P_{IN} = 0 \,^{\circ}\text{dBm}$, Supply Voltage $V_{IO} = 1.65...1.95\text{V}$, unless otherwise specified. Open ports are terminated with $50 \, \Omega$.

Parameter	Symbol		Values		Unit	Note / Test Condition	
		Min.	lin. Typ.				
Insertion Loss ¹⁾		•					
		_	0.30	0.43	dB	698-960 MHz	
		_	0.38	0.48	dB	1428-1920 MHz	
All TDy Dowle		_	0.41	0.49	dB	1990-2170 MHz	
All TRX POILS	IL	_	0.46	0.55	dB	2170-2690 MHz	
		-	0.70	0.79	dB	3400-3600 MHz	
		-	0.80	0.85	dB	3600-3800 MHz	
		-	1.30	1.45	dB	5000-6000 MHz	
Return Loss ¹⁾	•						
		22	26	-	dB	698-960 MHz	
		21	25	-	dB	1428-1920 MHz	
All TDy Dorto	RL	20	23	-	dB	1990-2170 MHz	
All TRX POILS	KL	16	20	-	dB	2170-2690 MHz	
		13	16	-	dB	3400-3600 MHz	
		12	15	_	dB	3600-3800 MHz	
		8	12	-	dB	5000-6000 MHz	
Isolation ^{1) 2)}					•		
		39	50	_	dB	698-960 MHz	
		33	43	-	dB	1428-1920 MHz	
All TDy Dorts	ISO	32	49	-	dB	1990-2170 MHz	
Insertion Loss ¹⁾ All TRx Ports Return Loss ¹⁾ All TRx Ports Isolation ^{1) 2)} All TRx Ports Harmonic Generation (UMTS B 2 nd harmonic generation 3 rd harmonic generation (Unit of the company	150	30	37	-	dB	2170-2690 MHz	
		28	34	-	dB	3400-3600 MHz	
		28	33	-	dB	3600-3800 MHz	
		22	27	-	dB	5000-6000 MHz	
Harmonic Generation (UMTS	Band 1, Band 5)	1)					
2 nd harmonic generation	P _{H2}	_	-80	-69	dBm	27 dBm, 50 Ω, CW mod	
3 rd harmonic generation	P _{H3}	_	-60	-59	dBm	27 dBm, 50 Ω, CW mod	
Intermodulation Distortion (UMTS Band 1, B	and 5) ¹⁾	•	•	•		
2 nd order intermodulation	IMD2 low ³⁾	_	-	-110	dBm	IMT, US Cell (see Tab. 7	
3 rd order intermodulation	IMD3	_	_	-110	dBm	IMT, US Cell (see Tab. 8	
2 nd order intermodulation	IMD2 high	_	_	-110	dBm	IMT, US Cell (see Tab. 7)	

¹⁾On application board without any matching components.

²⁾Isolation to inactive ports when one path is active.

 $^{^{\}rm 3)}\mbox{With 27 nH}$ shunt inductor at the ANT.

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RF Characteristics

Table 6: Switching Time at $T_A = 25$ °C, $P_{IN} = 0$ dBm, Supply Voltage $V_{IO} = 1.65...1.95$ V, unless otherwise specified

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min. Typ. Max.		Max.		
Switching Time	,			,		•
RF Rise Time	t _{RT}	_	-	2	μs	10 % to 90 % RF signal
Switching Time	t _{ST}	_	3	4.5	μs	50% last SCLK falling edge to 90% RF signal, see Fig. 1
Power Up Settling Time	t _{Pup}	_	10	25	μs	After power down mode

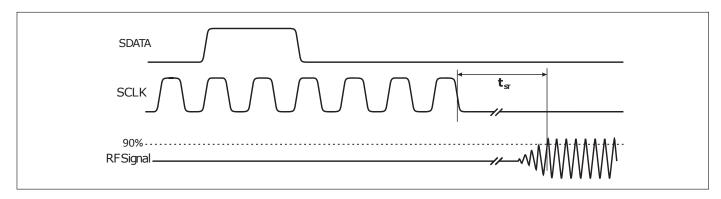


Figure 1: MIPI to RF time

Table 7: IMD2 Testcases

Band	CW tone 1 (MHz)	CW tone 1 (dBm)	CW tone 2 (MHz)	CW tone 2 (dBm)
IMT	1950	20	190 (IMD2 low)	-15
IIVI I	1950	20	4090 (IMD2 high)	-13
US Cell	835	20	45 (IMD2 low)	15
03 Cell		20	1715 (IMD2 high)	-15

Table 8: IMD3 Testcases

Band	CW tone 1 (MHz)	CW tone 1 (dBm)	CW tone 2 (MHz)	CW tone 2 (dBm)
IMT	1950	20	1760	-15
US Cell	835	20	790	-15

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MIPI RFFE Specification

5 MIPI RFFE Specification

All sequences are implemented according to the 'MIPI Alliance Specification for RF Front-End Control Interface' document version 2.0 - 25. September 2014.

Table 9: MIPI Features

Feature	Supported	Comment
MIPI RFFE 1.10 and 2.0 standards	Yes	
Register 0 write command sequence	Yes	
Register read and write command sequence	Yes	
Extended register read and write command se-	Yes	
quence		
Support for standard frequency range operations	Yes	Up to 26 MHz for read and write
for SCLK		
Support for extended frequency range operations	Yes	Up to 52 MHz for write ¹⁾
for SCLK		
Half speed read	Yes	
Full speed read	Yes	
Full speed write	Yes	
Programmable Group SID	Yes	
Trigger functionality	Yes	
Broadcast / GSID write to PM TRIG register	Yes	
Reset	Yes	Via VIO, PM TRIG or software register ¹⁾
Status / error sum register	Yes	
Extended product ID register	Yes	
Revision ID register	Yes	
Group SID register	Yes	
USID_Sel pin	No	External pin for changing USID is not implemented

¹⁾ only supported by MIPI 2.0 Standard

Table 10: Startup Behavior

Feature	State		Comment
Power status	Power	down	Power down mode after start-up
	mode		
Trigger function	Enabled		Enabled after start-up. Programmable via behavior control register

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MIPI RFFE Specification

Table 11: Register Mapping, Table I

Register Address	Register Name	Data Bits	Function	Description	Default	Broadcast_ID Support	Trigger Support	R/W
0x00	SW_CTRL0	6:0	SW_CTRL0	RF Switch Control	0	No	Yes	R/W
0x1C	PM_TRIG	7	PWR_MODE(1), Operation Mode	0: Normal operation (ACTIVE)	1	Yes	No	R/W
				1: Low Power Mode (LOW POWER)	-			
		6	PWR_MODE(0), State Bit Vector	0: No action (ACTIVE)	0			
				1: Powered Reset (STARTUP to ACTIVE to LOW POWER)				
		5	TRIGGER_MASK_2	0: Data masked (held in shadow REG)	0	No		
				1: Data not masked (ready for transfer to active REG)				
		4	TRIGGER_MASK_1	0: Data masked (held in shadow REG)	0			
				1: Data not masked (ready for transfer to active REG)				
		3	TRIGGER_MASK_0	0: Data masked (held in shadow REG)	0			
				1: Data not masked (ready for transfer to active REG)				
		2	TRIGGER_2	0: No action (data held in shadow REG)	0	Yes		
				1: Data transferred to active REG				
		1	TRIGGER_1	0: No action (data held in shadow REG)	0			
				1: Data transferred to active REG				
		0	TRIGGER_0	0: No action (data held in shadow REG)	0			
				1: Data transferred to active REG				
0x1D	PRODUCT_ID	7:0	PRODUCT_ID	This is a read-only register. However, during the programming of the USID a write command sequence is performed on this register, even though the write does not change its value.	0xCC	No	No	R
0x1E	MAN_ID	7:0	MANUFACTURER_ID [7:0]	This is a read-only register. However, during the programming of the USID, a write command sequence is performed on this register, even though the write does not change its value.	0x1A	No	No	R
0x1F	MAN_USID	7:6	RESERVED	Reserved for future use	00	No	No	R
		5:4	MANUFACTURER_ID [9:8]	These bits are read-only. However, during the programming of the USID, a write command sequence is performed on this register even though the write does not change its value.	01			
		3:0	USID[3:0]	Programmable USID. Performing a write to this register using the described programming sequences will program the USID in devices supporting this feature. These bits store the USID of the device.	0x9	No	No	R/W

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MIPI RFFE Specification

Table 12: Register Mapping, Table II

Register Address	Register Name	Data Bits	Function	Description	Default	Broadcast_ID Support	Trigger Support	R/W
0x20	EXT_PROD_ID ¹⁾	7:0	EXT_PRODUCT_ID		0x00	No	No	R
0x21	REV_ID	7:4	MAIN_REVISION		0x4	No	No	R/W
		3:0	SUB_REVISION		0x0	1		
0x22	GSID ¹⁾	7:4	GSID0[3:0]	Primary Group Slave ID.	0x0	No	No	R/W
		3:0	RESERVED	Reserved for secondary Group Slave ID.	0x0			
0x23	UDR_RST	7	UDR_RST	Reset all configurable non-RFFE Reserved registers to default values. 0: Normal operation 1: Software reset	0	No	No	R/W
		6:0	RESERVED	Reserved for future use	0000000	1		
0x24	ERR_SUM ¹⁾	7	RESERVED	Reserved for future use	0	No	No	R
		6	COMMAND_FRAME_PAR_ERR	Command Sequence received with parity error — discard command.	0			
		5	COMMAND_LENGTH_ERR	Command length error.	0			
		4	ADDRESS_FRAME_ PAR_ERR	Address frame with parity error.	0			
		3	DATA_FRAME_PAR_ERR	Data frame with parity error.	0			
		2	READ_UNUSED_REG	Read command to an invalid address.	0			
		1	WRITE_UNUSED_REG	Write command to an invalid address.	0			
		0	BID_GID_ERR	Read command with a BROADCAST_ID or GROUP_ID.	0			

¹⁾Only supported by MIPI 2.0 Standard

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MIPI RFFE Specification

Table 13: Modes of Operation (Truth Table, Register_0)

Value (Bin.)	Mode
00000000	ALL OFF (Isolation)
0000001	RF1 ON
00000010	RF2 ON
00000100	RF3 ON
00001000	RF4 ON
00010000	RF5 ON
00100000	RF6 ON
	00000000 00000001 00000010 00000100 00001000

¹⁾Chip state is 0 (isolation) in unused states

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Package related information

6 Package related information

The switch has a package size of 1100 μ m in x-dimension and 1900 μ m in y-dimension with a maximum deviation of \pm 50 μ m in each dimension. Fig. 2 shows the footprint from top view. The definition of each pin can be found in Tab. 15.

Table 14: Mechanical Data

Parameter	Symbol	Value	Unit
Package X-Dimension	X	1100 ± 50	μm
Package Y-Dimension	Υ	1900 ± 50	μm
Package Height	Н	0.65 max	μm

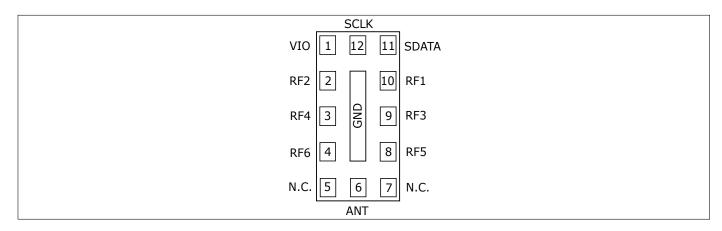


Figure 2: Footprint, top view

Table 15: Pin Definition

No.	Name	Pin Type	Function
1	VIO	Power	MIPI RFFE Power Supply
2	RF2	RF	RF-Port TRX No. 2
3	RF4	RF	RF-Port TRX No. 4
4	RF6	RF	RF-Port TRX No. 6
5	N.C.	na	Not connected
6	ANT	RF	RF Antenna Port
7	N.C.	na	Not connected
8	RF5	RF	RF-Port TRX No. 5
9	RF3	RF	RF-Port TRX No. 3
10	RF1	RF	RF-Port TRX No. 1
11	SDATA	I/O	MIPI RFFE Data I/O
12	SCLK	I/O	MIPI RFFE Clock
GND	GND	Ground	Ground (center pin)

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Package related information

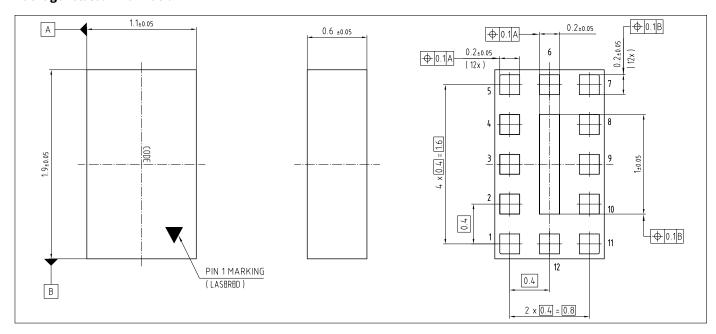


Figure 3: Package Outline Drawing (top, side and bottom views)

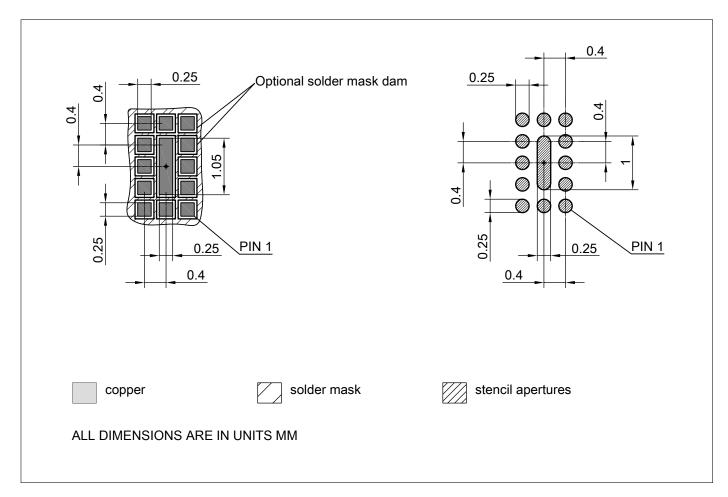


Figure 4: Land Pattern Drawing

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Package related information

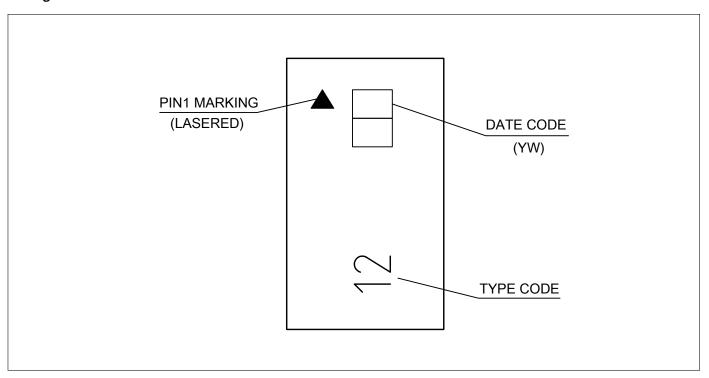


Figure 5: Laser marking

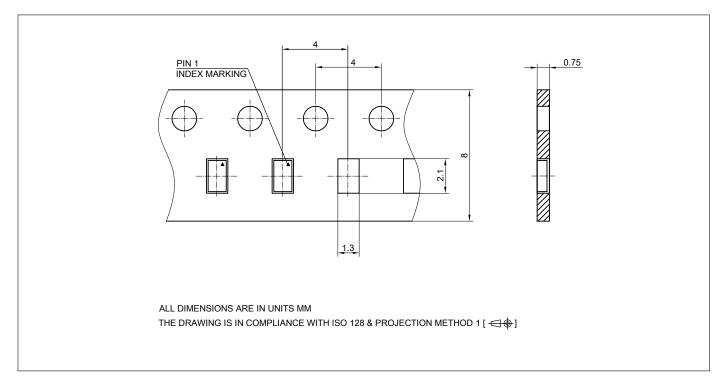


Figure 6: Carrier Tape

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Package related information

Table 16: Year date code marking - digit "Y"

I UDIC 10	. icai aac	c couc iii	urking u	igit i	
Year	"Y"	Year	"Y"	Year	"Υ"
2000	0	2010	0	2020	0
2001	1	2011	1	2021	1
2002	2	2012	2	2022	2
2003	3	2013	3	2023	3
2004	4	2014	4	2024	4
2005	5	2015	5	2025	5
2006	6	2016	6	2026	6
2007	7	2017	7	2027	7
2008	8	2018	8	2028	8
2009	9	2019	9	2029	9

Table 17: Week date code marking - digit "W"

			_	_					
Week	"W"								
1	Α	12	N	23	4	34	h	45	V
2	В	13	Р	24	5	35	j	46	x
3	C	14	Q	25	6	36	k	47	у
4	D	15	R	26	7	37	l	48	z
5	E	16	S	27	a	38	n	49	8
6	F	17	T	28	b	39	р	50	9
7	G	18	U	29	С	40	q	51	2
8	н	19	V	30	d	41	r	52	3
9	J	20	W	31	e	42	S		
10	K	21	Υ	32	f	43	t		
11	L	22	Z	33	g	44	u		

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